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## The role of A-site composition in the photostability of tin–lead perovskite solar cells†

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The efficiency of tin–lead perovskite solar cells (TLPSC) has been consistently increasing. However, their photostability continues to be a persistent challenge. Besides the oxidation of tin (Sn), the presence of methylammonium (MA) has been correlated with poor device photostability, which still remains unclear. In this work, we unravel the influence of the A-site cation choice, MA vs. cesium (Cs), on the photostability and performance of TLPSCs where  $\text{Cs}_{0.25-x}\text{MA}_x\text{FA}_{0.75-x}\text{Sn}_{0.5}\text{Pb}_{0.5}\text{I}_3$  (FA: formamidinium;  $x = 0.0-0.25$ ) is used as a photoactive layer. We observe that the addition of MA (*i.e.* increasing  $x$ ) improves the device efficiency while reducing the photostability. This reduction is attributed to light-induced interfacial barriers, surface recombination, and ion diffusion. We found that MA volatilizes from the surface of MA-rich devices during illumination, leading to an irreversible performance loss after light exposure. We further demonstrate that MA content rather than the choice of the hole-transport layer (PEDOT:PSS vs.  $\text{NiO}_x$ ) dominates the device photostability. Under continuous 1 sun illumination, devices without MA and with the use of  $\text{NiO}_x$  as a transport layer are able to retain 80% of their efficiency for 690 h, while MA-rich cells retain 80% of their efficiency only for the first 3 h of operation. Our work provides insights into the development of photostable TLPSC.

## Introduction

In the last decade, tin–lead perovskite solar cells (TLPSCs) have witnessed a continuous and rapid development with state-of-the-art devices achieving efficiencies above 20%.<sup>1–6</sup> In contrast to pure lead (Pb) or tin (Sn) perovskites, their combination results in a narrower bandgap that is defined according to the Sn:Pb ratio. For bandgaps between 1.2 and 1.3 eV, the common Sn : Pb ratio is found to be around 0.4 : 0.6 and 0.7 : 0.3.<sup>7,8</sup> This

is advantageous as TLPSCs possess a higher Shockley–Queisser limit than Pb based perovskites. They are promising for bottom cells in all-perovskite tandem solar cells, where efficiencies above 30% are predicted.<sup>9–12</sup> Additionally, the lower content of Pb decreases the environmental toxicity of perovskite solar cells (PSCs).<sup>13</sup> The Sn–Pb systems are more stable when compared to pure Sn perovskites because of the reduced Sn content and the stabilizing effect of Pb substitution in the lattice.<sup>14</sup>

The long-term stability of TLPSCs under operating conditions has been one of the major bottlenecks for further development of this technology. The main contributors include the oxidation of Sn, unstable hole-transport layer (HTL), and the presence of methylammonium (MA) content in the perovskite. The most typical explanation for the limited stability is the easy oxidation of  $\text{Sn}^{2+}$  to  $\text{Sn}^{4+}$ . Initially, the Sn oxidation results in a self-doping effect that increases the electrical conductivity, reduces the diffusion length, and favors non-radiative recombination.<sup>15–17</sup> On a longer time scale, this can trigger the formation of different byproducts that hinder device efficiency.<sup>18–20</sup> The most common strategy to overcome this limitation consists of employing different additives or dopants, which help preventing the oxidation of  $\text{Sn}^{2+}$  or reduce the  $\text{Sn}^{4+}$  already present in the system.<sup>9,21,22</sup> Likewise, the selection of a stable HTL has become increasingly more important. The usual architecture for TLPSCs is the p–i–n configuration, where PEDOT:PSS is the most common HTL so far. However, it has been shown that under operating conditions, the interface between PEDOT:PSS and the perovskite presents signs of degradation.<sup>23</sup> Different approaches to minimize this issue include the removal of the HTL<sup>23–25</sup> or the use of other HTLs such as  $\text{NiO}_x$  or PTAA.<sup>26–29</sup>

Another critical aspect of the device stability is the selection of the A-site cation, namely Cs, MA, and formamidinium (FA). Devices based on the typical MAFA double cation or the CsMAFA triple cation compositions have consistently retained >95% of their original PCE after 1000 hours under dark and inert conditions.<sup>4,30–34</sup> However, upon light illumination, efficiency losses of around 10% already exist after 450 h under 1

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sun.<sup>6</sup> In contrast, MA-free devices based on the CsFA mixture maintained their initial efficiency even after 1000 h of operation under 1 sun at 85 °C.<sup>23</sup> Further work has also shown that CsFA devices remain stable for 4000 h at 85 °C.<sup>28</sup> Hence, MA plays a critical role in the photostability or the thermal stability, which has also been observed for Pb and Sn-only compositions.<sup>35,36</sup> Although this is commonly attributed to the highly volatile nature of MA,<sup>37,38</sup> this issue has not been thoroughly studied in TLPSCs. Therefore, a more in-depth understanding of the role of cation compositions in performance and photo-degradation is needed to enable the rational design of stable TLPSCs.

In this work, we investigate the role of MA in the efficiency and photostability of TLPSCs. To explore the effect of MA, we choose the perovskite composition  $\text{Cs}_{0.25-x}\text{MA}_x\text{FA}_{0.75}\text{Sn}_{0.5-x}\text{Pb}_{0.5}\text{I}_3$  where the content of MA is given by  $x = 0, 0.10, 0.20,$  and  $0.25$ . The addition of MA improves the overall performance of the cells; however, it results in a sharp and permanent decrease in the efficiency during the first hour of 1 sun illumination. To understand this rapid and irreversible decay in performance, we carried out light-intensity dependent measurements and impedance spectroscopy. We found that at higher contents of MA ( $x = 0.25$ ), the devices suffered from increased surface recombination, and high mobile ion density after light exposure. Moreover, X-ray and UV photoemission experiments present evidence of MA volatilization at the surface of the  $x = 0.25$  films after continuous illumination, which is correlated to the creation of extraction barriers at the perovskite and electron transport layer (ETL) interface. To further understand what is the limiting factor in the photostability of TLPSCs, we tested devices with and without MA by using two different hole transport layers (HTLs), PEDOT:PSS and  $\text{NiO}_x$ . Devices with only MA ( $x = 0.25$ ) exhibited a performance drop higher than 30% after 15 hours under illumination, regardless of the HTL, whereas MA-free devices ( $x = 0$ ) retained 80% of the original PCE after 550 h and 690 h for PEDOT:PSS and  $\text{NiO}_x$ , respectively. In comparison to the surface oxidation of Sn or HTL selection, our results confirm that MA content is the most critical factor for device photostability in TLPSCs.

## Experimental section

### Materials

CsI (dry beads 99.999%),  $\text{PbI}_2$  (dry beads, 99.999%),  $\text{SnI}_2$  (99.99%),  $\text{SnF}_2$ , bathocuproine (BCP), DMSO, and DMF (both anhydrous) were purchased from Sigma Aldrich. MAI and FAI were provided by Greatcell and TCI, respectively.  $\text{C}_{60}$  was supplied by nanoC.  $\text{NiO}_x$  nanoparticle (7 nm) solution in ethanol was provided by Avantama. PEDOT:PSS AI 4083 was obtained from Heraeus.

### Device fabrication

Pre-patterned ITO/glass substrates (Xinyan Technology, 10/15  $\Omega \text{sq}^{-1}$ , CN) were sequentially sonicated in a Hellmanex aqueous solution, deionized water, acetone, and isopropanol for 10 min each. Substrates were dried with  $\text{N}_2$  and treated with UV ozone

for 15 min. The  $\text{NiO}_x$  nanoparticle solution was spin coated at a speed of 4000 rpm for 30 s, followed by annealing at 300 °C for 30 min; the thickness of the  $\text{NiO}_x$  measured by atomic force microscopy was  $\sim 5$  nm. For the devices that utilized PEDOT:PSS as the HTL, a solution of PEDOT and isopropanol (1 : 1) was coated on the clean ITO at 4000 rpm for 30 s and then annealed at 150 °C for 10 min. After HTL deposition, the samples were transferred to a  $\text{N}_2$  glovebox. The perovskite precursor solution was prepared by dissolving the precursor salts of CsI, MAI, FAI,  $\text{PbI}_2$ ,  $\text{SnI}_2$  and  $\text{SnF}_2$  (10 mol% with respect to  $\text{SnI}_2$ ) in DMF : DMSO (3 : 1) according to the formula  $\text{Cs}_{0.25-x}\text{MA}_x\text{FA}_{0.75}\text{Sn}_{0.5-x}\text{Pb}_{0.5}\text{I}_3$ ; the intended concentration was 1.6 M, and the solution was stirred for 1 h at room temperature. A two-step spin-coating procedure of 1000 rpm for 10 s and 4000 rpm for 40 s was used for the deposition of the perovskite films. Chlorobenzene (100  $\mu\text{l}$ ) is added at the 20th s of the 2<sup>nd</sup> step. After this, the samples were annealed at 100 °C for 10 min. Subsequently,  $\text{C}_{60}$  (30 nm) and BCP (8 nm) were thermally evaporated at a rate of 0.1  $\text{A s}^{-1}$  under high vacuum by using an Angstrom Engineering system. Finally, 100 nm of Ag was thermally evaporated to obtain devices with an area of 0.1  $\text{cm}^2$ .

### Device characterization

A LED solar simulator (WaveLabs Sinus-70, Greater than AAA rated) calibrated to  $\pm 5\%$  of AM1.5G between 350 and 1100 nm was used to obtain current–voltage curves and for the light-soaking experiments. For light intensity dependent measurements, several neutral-density filters from Thorlabs were used to attenuate the simulated sunlight. To record the  $J$ - $V$  response, a Keithley 2400-series source-measure unit was used with a scan speed of 0.15  $\text{V s}^{-1}$ . For the short-term stability measurements, a  $J$ - $V$  curve was recorded each 10 min while devices were left under illumination (AM1.5G) and open-circuit conditions. For the entire duration of the measurement, devices were in a  $\text{N}_2$  glovebox ( $< 0.1$  ppm). For the long-term photostability measurements, solar cells were placed inside an environmental chamber and purged with a constant flow of nitrogen. This chamber was placed under a bank of metal halide lamps (Osram Powerstar HQI, 900 W) with a total intensity of approximately 1 sun. A thermoelectric chiller was used to cool the cells to a temperature of 40 °C throughout the light soaking experiment. Each solar cell was connected to an individual source-measure unit (based on the open-source “ $\mu\text{SMU}$ ” design available at <https://certification.oshwa.org/sa000002.html>) calibrated against a Keithley 2400. Current–voltage curves were measured at 10 minute intervals from  $J_{\text{sc}}$  to  $V_{\text{oc}}$ , with each device held at its maximum power point in-between measurements. Impedance spectroscopy measurements were performed with a Fluxim Paios characterization suite. The impedance signal was recorded in the 0.1 Hz to 10 MHz frequency range with a 10 mV amplitude voltage inside a  $\text{N}_2$  glovebox in the dark.

### Film characterization

SEM pictures were taken with a Zeiss Auriga microscope. UV-Vis measurements were carried out with a Perkin Lambda 850 UV/



Vis spectrophotometer. Ultra-violet and X-ray photoelectron spectroscopy (UPS/XPS) measurements were performed in an ultrahigh vacuum chamber ( $\sim 10^{-10}$  mbar) built by Scienta Omicron, using a hemispherical electron analyzer (Sphera II EAC 125 7-channeltron). The analyzer was calibrated with the Fermi edge of polycrystalline silver cleaned using argon sputtering. UPS measurements were performed using a He I line with an excitation energy of 21.22 eV and a pass energy of 5 eV. The work function of the samples was determined from the secondary electron cut-off of the UPS spectrum, as the difference between the excitation energy and the length of the spectrum.<sup>39</sup> All XPS measurements were performed using a monochromatized AlK (excitation energy of 1486.6 eV) operated at 15 kV. XPS high-resolution spectra were recorded at a pass energy of 10 eV, respectively, and referenced to the carbon 1s peak at 284.8 eV. The samples for XPS and UPS measurements were prepared by depositing the respective perovskite solution on ITO/NiO<sub>x</sub> substrates under equal conditions as explained in the device fabrication section. Then, fresh samples were kept in the dark, while light-soaked samples were under AM 1.5G (WaveLabs Sinus-70) for 6 hours; during this process, the samples were kept under N<sub>2</sub>. The X-ray diffraction (XRD) experiment was performed with a Bruker D8 advanced diffractometer.

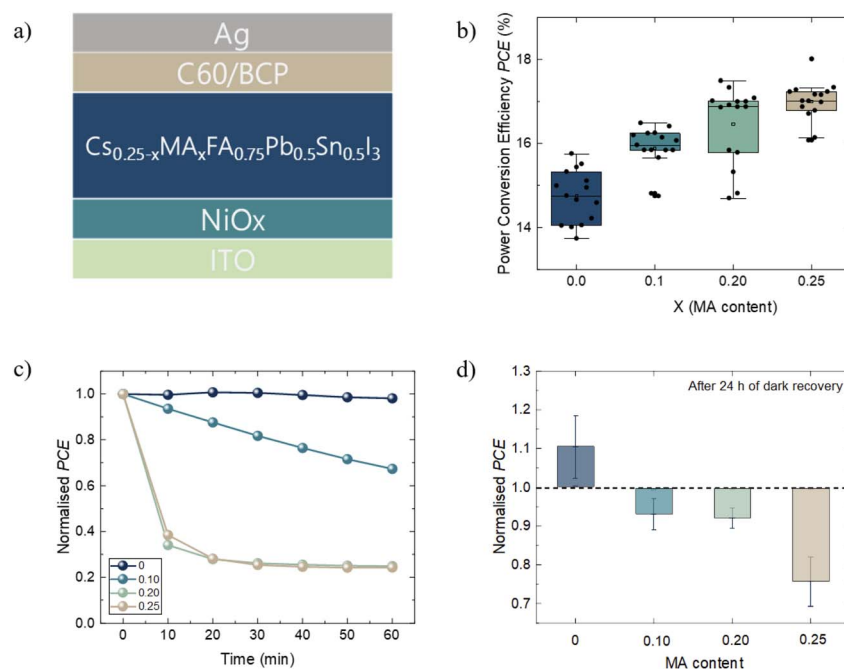
## Results and discussion

PSCs with the device architecture ITO/NiO<sub>x</sub>(5 nm)/Cs<sub>0.25-x</sub>MA<sub>x</sub>FA<sub>0.75</sub>Sn<sub>0.5</sub>Pb<sub>0.5</sub>I<sub>3</sub> ( $x = 0, 0.10, 0.20, \text{ and } 0.25$ ) (700 nm)/C<sub>60</sub> (30 nm)/BCP (8 nm)/Ag (100 nm) were fabricated (Fig. 1a). The

films of each composition presented a pin-hole free morphology and a similar grain size of  $\sim 500$  nm (Fig. S1†). The PCE increases with the increase in MA content, resulting in enhancement of the average PCE from 14.80 ( $x = 0$ ) to 16.76 ( $x = 0.25$ ) (Fig. 1b, Table 1). The improvement is due to enhanced fill factor (FF) and open-circuit voltage ( $V_{oc}$ ) at higher MA content (Fig. S2†). The short-circuit current density ( $J_{sc}$ ) data are in agreement with the values obtained from external quantum efficiency (EQE) measurements (Fig. S3†). Moreover, the forward and reverse scans present a visible increase in hysteresis at higher  $x$  values (Fig. S4†). In the Pb-based PSC, the use of MA to boost the FF and  $V_{oc}$  has been rationalized due to longer carrier diffusion lengths at higher quantities of MA.<sup>40,41</sup> A longer diffusion length allows for a more effective charge extraction and sufficient light-harvesting. In Sn-Pb perovskites, longer diffusion lengths are observed for MAFA compared to CsFA-based compositions,<sup>1,10</sup> suggesting that the inclusion of MA in TLPSCs follows a similar trend to a Pb-based PSC. Additionally,

**Table 1** Photovoltaic parameters of Cs<sub>0.25-x</sub>MA<sub>x</sub>FA<sub>0.75</sub>Sn<sub>0.5</sub>Pb<sub>0.5</sub>I<sub>3</sub> devices; 15 devices were fabricated for each composition. Numbers shown are the average values, while values in parentheses are champion devices

$x$	$J_{sc}$ (mA cm <sup>-2</sup> )	$V_{oc}$ (V)	FF	PCE (%)
0	32.53 (32.71)	0.66 (0.68)	0.68 (0.69)	14.80 (15.51)
0.1	31.25 (31.81)	0.73 (0.73)	0.70 (0.71)	15.88 (16.49)
0.2	30.98 (30.78)	0.76 (0.78)	0.70 (0.72)	16.47 (17.34)
0.25	29.76 (31.19)	0.79 (0.79)	0.71 (0.72)	16.77 (18.01)



**Fig. 1** (a) p-i-n device architecture of TLPSCs. (b) PCEs of corresponding devices at different MA contents represented as X. (c) Normalised PCEs of devices as a function of time at AM1.5G in a N<sub>2</sub> environment; devices were left under open circuit conditions for the whole duration of the measurement (the PCE was obtained from Fig. S6†). (d) Normalised performance gain/loss of devices measured before and 24 h after light stability tests; devices were left in the dark during the recovery time.



ultraviolet photoemission spectroscopy (UPS) measurements (discussed later in the text) showed a favorable energy alignment between NiO<sub>x</sub> and the perovskite ionization energies (IEs) when  $x = 0.25$  but not at  $x = 0$  (Fig. S5†). The IE mismatch observed for  $x = 0$  results in formation of an energetic barrier that impedes efficient hole extraction, causing the observed lower  $V_{oc}$ .

The photostability of the devices was tested by recording  $J$ - $V$  curves for each perovskite composition every 10 min for 1 hour under AM1.5G (Fig. S6†), leaving the devices under open-circuit conditions. The normalized PCEs of representative devices are presented in Fig. 1c. For the devices with higher content of MA ( $x = 0.25$  and  $x = 0.20$ ), we observed a PCE loss of 60% during the first 10 min of operation. After this sudden drop, the efficiency remained relatively stable. The PCE drop was less severe for  $x = 0.10$ ; however, the stabilization of the PCE was not observed throughout the measurement duration. In contrast, the devices without MA ( $x = 0$ ) did not present significant PCE loss and remained stable during the complete duration of the measurement. The performance loss in MA-based devices was previously shown to be reversible, and this was attributed to thermally generated carriers caused during illumination.<sup>12</sup> An alternative explanation for the performance drop was given due to mobile ions screening the built-in potential during the early stages of illumination.<sup>42</sup> To verify the possible degradation pathway of the cells, we measured the recovery of our devices after 24 h after the light stability test. During recovery, the devices were stored in the dark in a N<sub>2</sub> filled glovebox. The devices without MA ( $x = 0$ ) exhibited a 10% efficiency improvement after the recovery time (Fig. 1d). For the intermediate compositions ( $x = 0.10$  and  $x = 0.20$ ), a nearly full

recovery of their PCE is observed. In comparison, the devices with only MA ( $x = 0.25$ ) lost around 25% of their initial efficiency. This irreversible performance loss indicates that thermally generated carriers are not responsible for the device degradation; instead, our findings align better with the hypothesis of light-induced ionic motion, which can further incite irreversible chemical reactions.<sup>37,43</sup> To ensure this performance loss was due to light-soaking and not intrinsic instability of the device, we measured the shelf stability of only MA ( $x = 0.25$ ) devices and found that 90% of their initial PCE was retained for at least 100 h (Fig. S7†). These results suggest that the inclusion of MA reduces the photostability and leads to an irreversible loss of performance after 1 h under illumination. To better understand the mechanisms leading to significant differences in the photostability of the devices, we further analyze the principal recombination mechanisms, the charge transport behavior and the surface chemistry of fresh and light-soaked samples with  $x = 0$  and  $x = 0.25$  compositions, henceforth denoted as CsFA ( $x = 0.0$ ) and MAFA ( $x = 0.25$ ).

Light-intensity dependent measurements can provide information regarding the recombination kinetics in a solar cell. The relation between  $V_{oc}$  and light intensity  $I$  is given by  $V_{oc} = \left(\frac{nK_B T}{q}\right) \ln\left(\frac{I}{I_0} + 1\right)$ , where  $K_B$  is the Boltzmann constant,  $T$  is the temperature,  $q$  is the elementary charge, and  $n$  is the ideality factor. A value of  $n$  near 1 indicates band-to-band recombination or surface recombination, while an  $n$  of around 2 indicates that recombination is considered trap-assisted.<sup>44</sup> In the case of CsFA devices, they presented a minor increase in  $n$  from 1.25 to 1.29 after light soaking, which suggests that the recombination kinetics were not significantly influenced after

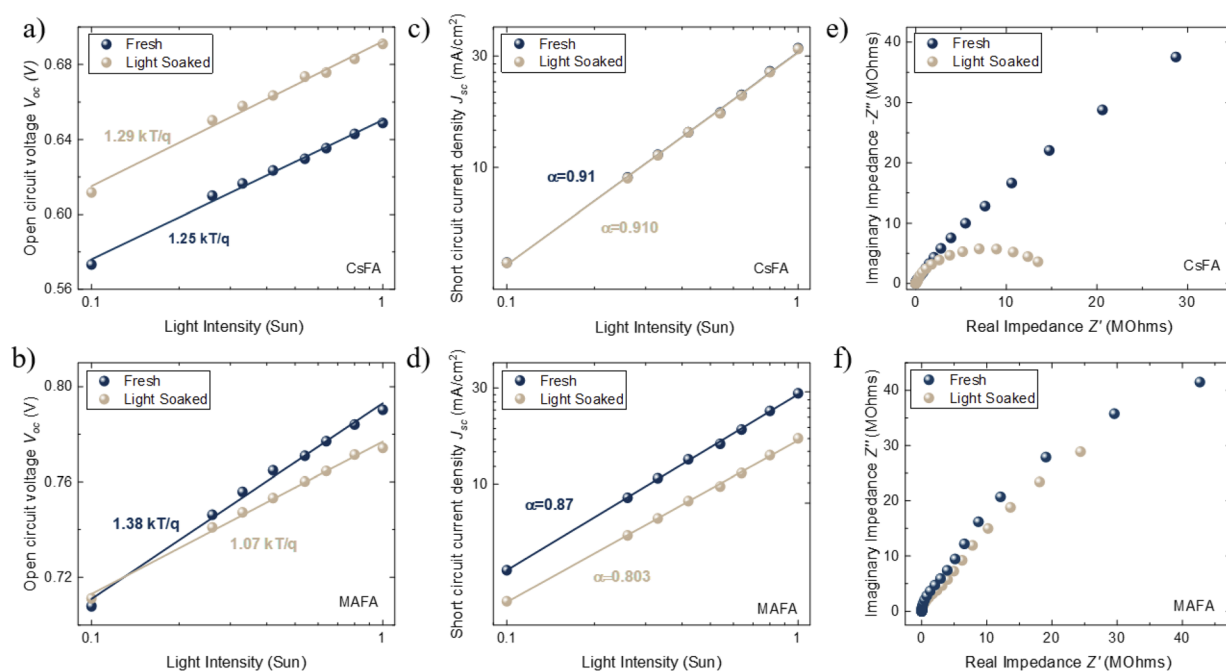


Fig. 2 (a and b) Light intensity-dependent  $V_{oc}$  measurements for CsFA and MAFA devices, (c and d) light intensity-dependent  $J_{sc}$  measurements for CsFA and MAFA devices, and (e and f) Nyquist plots derived from impedance spectroscopy measurements of CsFA and MAFA devices; measurements were taken in a N<sub>2</sub> atmosphere under dark conditions.



illumination (Fig. 2a). For the MAFA devices, the fresh and light-soaked samples exhibited a change of  $n$  from 1.38 to 1.07, respectively (Fig. 2b). We attribute this variation to increased surface recombination for the light-soaked samples.<sup>44</sup> Similarly, we studied the changes of  $J_{sc}$  against different light intensities. Here,  $J_{sc}$  and  $I$  are related through the power law given by  $J_{sc} \propto I^\alpha$ , where values of  $\alpha$  less than 1 are related to space charge effects or bimolecular recombination.<sup>45</sup> As expected, CsFA devices did not present significant changes in  $\alpha$  between fresh and light-soaked samples (Fig. 2c). In comparison, the MAFA devices showed a reduction in  $\alpha$  from 0.87 to 0.80 after light soaking, indicating that photocurrent in MAFA cells is limited by carrier imbalance or interfacial barriers (Fig. 2d).<sup>46</sup>

To understand the charge transport behavior before and after light soaking the devices, we conducted impedance spectroscopy (IS) measurements. IS allows to individually study the electronic and ionic contribution to the charge transport. Several studies demonstrate that ion conduction dominates at low frequencies, and the electronic contribution ensues at high frequencies.<sup>47–49</sup> The Nyquist plots from CsFA and MAFA reveal that ion diffusion has a significant contribution to charge transport (Fig. 2e and f). This phenomenon is characterized by a linear increase in the mid-frequency region and a line bending in the low and high-frequency regions.<sup>47</sup> We observed that ion diffusion in MAFA devices occurs regardless of being fresh or stressed by light. The ion motion could explain the steep drop in performance observed during our stability measurements of the MAFA device, as well as the increased surface recombination and the creation of interfacial barriers found in our light-intensity dependent measurements.<sup>42</sup> CsFA cells initially exhibited an ionic diffusion behavior; however, the light soaked devices presented a semicircle feature at mid and high frequencies, resulting in an improved efficiency after recovery.<sup>50</sup>

To study photoinduced changes in the electronic properties of perovskites, we performed UPS measurements. The IE of CsFA fresh samples was found to be 5.25 eV, with a minor change of 0.03 eV after light soaking, agreeing well with the observed photostable behavior. In comparison, light soaking resulted in a shift of 0.1 eV in the IE of MAFA samples, increasing from  $-5.54$  to  $-5.64$  eV, suggesting a possible change in surface composition. Using the optical bandgaps, the conduction band (CB) of the CsFA and MAFA was estimated to be  $-4.03$  and  $-4.32$  eV, respectively. Due to negligible changes in the optical bandgap after light soaking the MAFA films (Fig. S8†), the estimated CB was found to be lower (relative to the vacuum level) after the light soaking from  $-4.32$  to  $-4.42$  eV. Since the LUMO of  $C_{60}$  is known to be 4.3 eV,<sup>51</sup> the change in the CB of MAFA after light-soaking would result in an energetic barrier for electron transfer between MAFA and the  $C_{60}$  (Fig. 3a). No such energetic offset was found in the case of CsFA devices upon light soaking (Fig. 3b). The extraction barrier found in the MAFA/ $C_{60}$  interface justifies the reduced photostability observed as compared to the CsFA cells.

X-ray photoelectron spectroscopy (XPS) was performed to elucidate the irreversible performance loss of the MAFA devices and to check prolonged photo-induced changes in the chemical composition at the perovskite surface as possible degradation pathways. Noteworthy, no significant changes were detected for the amount of  $Sn^{4+}$  upon light soaking, indicating that the observed degradation is not due to the Sn oxidation at the surface. No further variations were observed in I and Pb peaks upon photodegradation (Fig. S9†). However, the C 1s peak was found to have four components at 284.8 eV, 286.3 eV, 288.2 eV and 289 eV attributed to (i) the adventitious carbon contamination, (ii)  $MA^+/C-O$ , (iii)  $FA^+$ , and (iv)  $PbCO_3$ ,<sup>52</sup> respectively (Fig. 3c). From all the components, only  $MA^+/C-O$  showed a significant drop of around

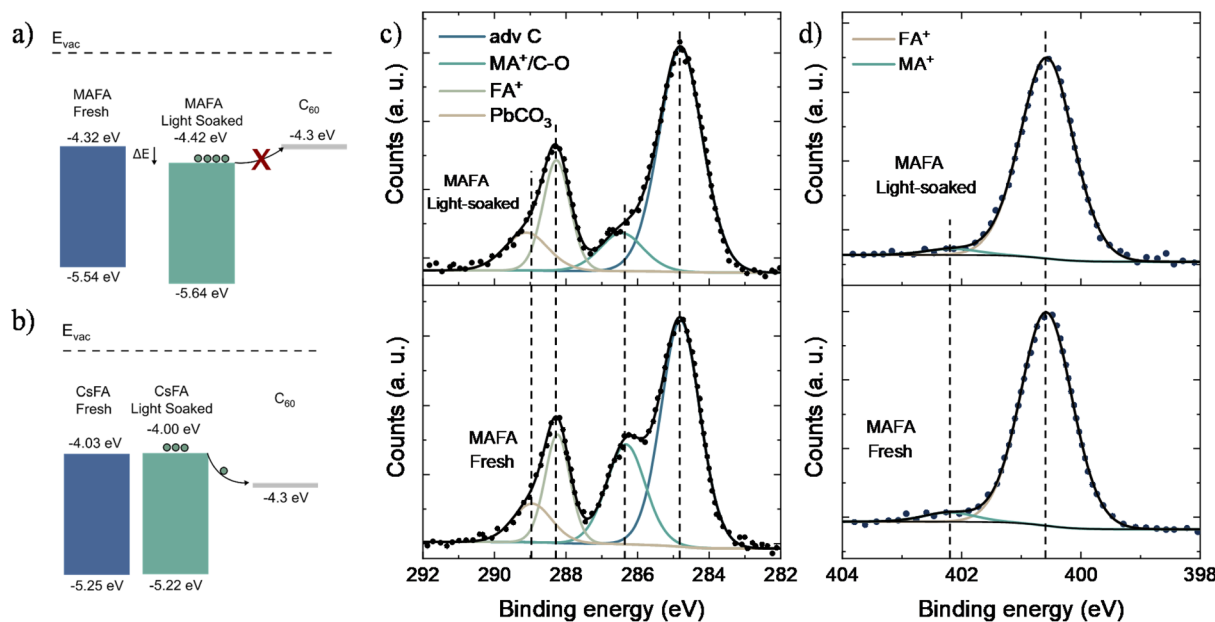


Fig. 3 (a) Band diagram of fresh and light soaked MAFA films highlighting the energy barrier between light soaked MAFA and  $C_{60}$ . (b) Band diagram of fresh and light soaked CsFA films. (c) XPS spectra showing the C 1s peaks of MAFA fresh and light soaked films for 6 h. (d) XPS spectra showing the N 1s peaks of MAFA fresh and light-soaked films for 6 h.



13%, accompanied by a chemical shift of 0.1 eV towards higher binding energy. This suggests that the degradation of MAFA samples results in the loss of total  $\text{MA}^+$ , potentially caused by the volatilization of MA from the MAFA film. The N 1s peak was found to be asymmetric, where the peaks at 400.6 eV and 402.2 eV are attributed to the nitrogen in  $\text{FA}^+$  (96%) and  $\text{MA}^+$  (4%), respectively (Fig. 3d) though no chemical shift in the N1s peak was observed upon photo-degradation; the amount of N1s associated with  $\text{MA}^+$  slightly reduced to  $\sim 3\%$ , in agreement with the changes observed for the C 1s peak attributed to  $\text{MA}^+$ . The C 1s spectra of CsFA films presented a reduction in the area  $\sim 4\%$  for the C–O component at 285.5 eV. In contrast to MAFA films, the N 1s spectra only reveal a single component at 400.6 eV attributed to the  $\text{FA}^+$  (Fig. S10†); no significant peak shifts were detected after light soaking. Similarly, the spectra of Pb, Sn, and I of CsFA films did not exhibit noteworthy changes upon light soaking (Fig. S11†). Considering the above findings, we conclude that irreversible loss of performance during the initial hours of operation in TLPSCs is mainly caused by the volatilization of MA at the perovskite surface. Furthermore, the X-ray diffraction (XRD) patterns of fresh and light soaked MAFA films reveal the presence of  $\text{PbI}_2$  (Fig. S12†). We did not find any correlation between peak intensity from the  $\text{PbI}_2$  signal and light soaking time, indicating that  $\text{PbI}_2$  is not formed due to illumination. In previous studies, presence of  $\text{PbI}_2$  has been associated with accelerated perovskite degradation under illumination.<sup>53</sup> In the case of fresh and light soaked CsFA

films, no  $\text{PbI}_2$  signal was detected. Hence, the  $\text{PbI}_2$  found in MAFA samples could result in another degradation pathway that is not present in the CsFA composition.

To explore the device degradation on a longer timescale, we tracked the photovoltaic performance of unencapsulated devices at the maximum power point (MPP) (details are provided in the ESI†). As a HTL,  $\text{NiO}_x$  has been considered a promising material since it has shown improved device stability compared to other polymeric HTLs.<sup>26,54,55</sup> In the particular case of TLPSCs, there is an absence of in-depth photostability studies to offer insights on the performance of  $\text{NiO}_x$  HTLs. To compare these results to state-of-the-art devices, we fabricated MAFA and CsFA cells with PEDOT:PSS as an alternative HTL. The average efficiencies obtained with PEDOT are 15.13% and 17.57% for CsFA and MAFA devices, respectively (Fig. S13†). Regardless of the HTL, the MAFA devices presented a fast decay in efficiency during the initial hours of the test. After 200 h, MAFA–PEDOT:PSS retained a slightly higher PCE of 65% of its initial value, compared to the 50% retained with the MAFA– $\text{NiO}_x$  cells. We note that MAFA– $\text{NiO}_x$  degrades faster than MAFA–PEDOT:PSS, which could be attributed to a MA deprotonation by  $\text{NiO}_x$ .<sup>55</sup> In both cases, significant losses were recorded for the  $J_{\text{sc}}$  and FF, indicating the formation of energetic barriers that inhibit the extraction of the photo-generated carriers.<sup>52</sup> CsFA–PEDOT:PSS cells retained a higher PCE than CsFA– $\text{NiO}_x$  devices during the first 450 hours. However, a faster

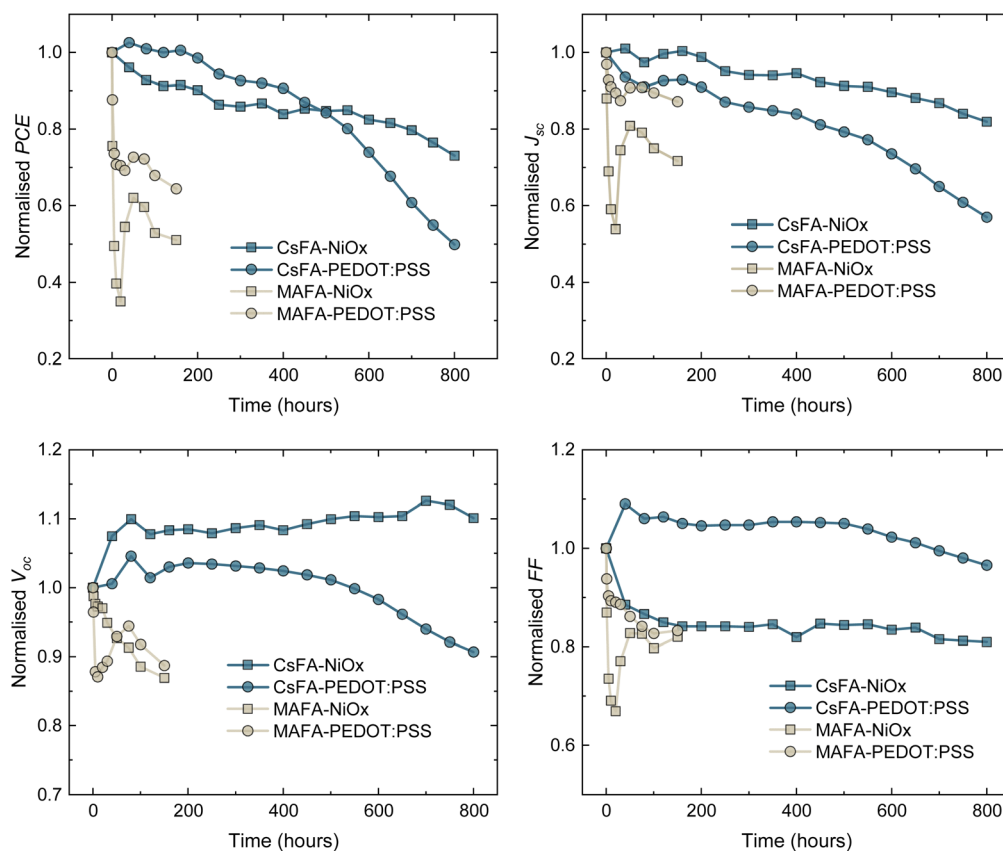


Fig. 4 Photovoltaic performance at 1 sun (metal halide lamp) as a function of time of unencapsulated MAFA and CsFA devices with  $\text{NiO}_x$  and PEDOT:PSS as the HTL.  $J$ - $V$ s were recorded each 10 min while devices were held at MPP under continuous  $\text{N}_2$  flow.



decay for the CsFA–PEDOT:PSS cells was recorded after this point. CsFA–NiO<sub>x</sub> devices retained 80% of their original PCE after 690 hours, whereas the PCE of CsFA–PEDOT:PSS cells dropped to 60% (Fig. 4). In both systems, the principal losses were observed for the  $J_{sc}$ , probably related to the Sn oxidation.<sup>20</sup> The lower stability of PEDOT:PSS compared to NiO<sub>x</sub> has been attributed to higher hydrophobicity and ITO etching due to the PEDOT:PSS acidity.<sup>54–57</sup> Comparing these results to the ones from Fig. 1d, the efficiency losses from MAFA devices held at the MPP were lower, while they remained stable for a considerably longer time. However, the trend of a faster efficiency decay for MAFA compared to CsFA remained the same. Overall, these results suggest that the A-site composition is more critical than the HTL during the early stages under operating conditions. In particular, the MA content in TLPSCs appears to be the bottleneck for photostable devices.

## Conclusion

In this work, we investigated the influence of A-site on the performance and photostability of TLPSCs. We found that the addition of MA improves the PCE while significantly compromising the device stability under working conditions. Our results indicate that light-induced interfacial barriers, surface recombination, and ion diffusion are responsible for the poor photostability of MA-rich devices during initial operational conditions. Additionally, we observed that MAFA devices present an irreversible loss of performance after illumination. We attribute this performance drop to the creation of an extraction barrier at the perovskite/ETL interface caused by the permanent volatilization of MA at the perovskite surface. Lastly, we found that the surface oxidation of Sn and the choice of the HTL have secondary roles in the short-term photostability of the device. However, the content of MA becomes a more critical factor towards the development of photostable TLPSCs. Since MA-based devices show high performance but inferior photostability, strategies focusing on reducing MA content or reducing ion migration will be beneficial for device photostability.

## Conflicts of interest

There are no conflicts of interests.

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